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CONTENTS

15 MARCH 1999-II

RAPID COMMUNICATIONS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

- Ambiguities in the parametrization of $4f^N$ - $4f^N$ electric-dipole transition intensities R7789
G. W. Burdick, S. M. Crooks, and M. F. Reid
- Reconstruction of the electronic structure in half-metallic CoS₂ R7793
R. Yamamoto, A. Machida, Y. Moritomo, and A. Nakamura

Semiconductors I: bulk

- Cooling dynamics of excitons in GaN R7797
D. Hägele, R. Zimmermann, M. Oestreich, M. R. Hofmann, W. W. Rühle, B. K. Meyer, H. Amano, and
I. Akasaki
- Coherent control for a two-level system coupled to phonons R7801
H. Castella and R. Zimmermann

Semiconductors II: surfaces, interfaces, microstructures, and related topics

- Manifestation of exciton-amplitude fluctuations in the transient polarization state of four-wave-mixing signals R7805
B. Haase, U. Neukirch, J. Gutowski, G. Bartels, A. Stahl, V. M. Axt, J. Nürnberger, and W. Faschinger
- Observation of combined electron and photon confinement in planar microcavities
incorporating quantum wires R7809
C. Constantin, E. Martinet, A. Rudra, and E. Kapon
- Electron-spin polarization near the Fermi level in n -type modulation-doped semiconductor quantum wells R7813
A. L. C. Triques, J. Urdanivia, F. Iikawa, M. Z. Maialle, J. A. Brum, and G. Borhgs
- Suppression of LO phonon scattering in Landau quantized quantum dots R7817
B. N. Murdin, A. R. Hollingworth, M. Kamal-Saadi, R. T. Kotitschke, C. M. Ciesla, C. R. Pidgeon,
P. C. Findlay, H. P. M. Pellemans, C. J. G. M. Langerak, A. C. Rowe, R. A. Stradling, and E. Gornik
- Reflection symmetry and quantized Hall resistivity near the quantum Hall transition R7821
D. N. Sheng and Z. Y. Weng
- Coulomb drag as a signature of the paired quantum Hall state R7825
Fei Zhou and Yong Baek Kim
- Skippping orbits and enhanced resistivity in large-diameter InAs/GaSb antidot lattices R7829
J. Eroms, M. Zitzlsperger, D. Weiss, J. H. Smet, C. Albrecht, R. Fleischmann, M. Behet, J. De Boeck, and
G. Borghs
- Suppression of Zeeman splitting in a GaAs quantum dot R7833
Soma Mukhopadhyay and Ashok Chatterjee



Inverse exciton series in the optical decay of an excitonic molecule	R7837
Eiji Tokunaga, A. L. Ivanov, Selvakumar V. Nair, and Yasuaki Masumoto	

Surface physics, low-dimensional systems, and related topics

Reduced oscillator strength in the lithium atom, clusters, and the bulk	R7841
Christoph Ellert, Martin Schmidt, Christina Schmitt, Hellmut Haberland, and Claude Guet	
Single-atom motion during a lateral STM manipulation	R7845
Xavier Bouju, Christian Joachim, and Christian Girard	
Quantum fluctuations in the cohesive force of metallic nanowires	R7849
C. Höppler and W. Zwerger	
Negative differential resistance in the scanning-tunneling spectroscopy of organic molecules	R7852
Yongqiang Xue, Supriyo Datta, Seunghun Hong, R. Reifengerger, Jason I. Henderson, and Clifford P. Kubiak	
Atomistic modeling of large-scale metal film growth fronts	R7856
U. Hansen, P. Vogl, and V. Fiorentini	

ARTICLES**Electronic structure: wide-band, narrow-band, and strongly correlated systems**

Fingered morphology of niobium (110) grown by molecular-beam epitaxy	7860
G. L. Zhou and C. P. Flynn	
Real-space full-multigrid study of the fragmentation of Li_{11}^+ clusters	7868
Francesco Ancilotto, Philippe Blandin, and Flavio Toigo	
Exact exchange-correlation potential for a time-dependent two-electron system	7876
Irene D'Amico and Giovanni Vignale	
Theory of pressure-induced phase transitions in cerium chalcogenides	7888
A. Svane, W. Temmerman, and Z. Szotek	
Band structure and Fermi surface of TmGa_3	7893
V. B. Pluzhnikov, A. Czopnik, G. E. Grechnev, N. V. Savchenko, and W. Suski	
Electronic structure of possible nickelate analogs to the cuprates	7901
V. I. Anisimov, D. Bukhvalov, and T. M. Rice	
Quantum Monte Carlo calculation of Compton profiles of solid lithium	7907
Claudia Filippi and David M. Ceperley	
Critical behavior in $\text{LaTiO}_{3+\delta/2}$ in the vicinity of antiferromagnetic instability	7917
Y. Taguchi, T. Okuda, M. Ohashi, C. Murayama, N. Môri, Y. Iye, and Y. Tokura	
Electronic structure of the gold complexes $\text{Cs}_2\text{Au}_2\text{X}_6$ ($X=\text{I}, \text{Br}, \text{and Cl}$)	7925
X. J. Liu, K. Matsuda, Y. Moritomo, A. Nakamura, and N. Kojima	
Ligand field parameters obtained from and chemical shifts observed at the $\text{Cr } L_{2,3}$ edges	7931
C. Theil, J. van Elp, and F. Folkmann	
Universal behavior of quantum impurity scattering in a Tomonaga-Luttinger liquid	7937
Yu-Liang Liu	
Pinning of the sliding collective charge state in a one-dimensional attractive fermion system	7950
Shu Chen, Yupeng Wang, Fan Yang, and Fu-Cho Pu	
Theoretical investigation of the geometric and optical properties of neutral and charged oligophenylenes	7957
E. Zojer, J. Cornil, G. Leising, and J. L. Brédas	
Theoretical search for Chevrel-phase-based thermoelectric materials	7969
R. W. Nunes, I. I. Mazin, and D. J. Singh	

Diagonal ladders: A class of models for strongly coupled electron systems	7973
G. Sierra, M. A. Martín-Delgado, S. R. White, D. J. Scalapino, and J. Dukelsky	
Semiconductors I: bulk	
Diffusion and transient trapping of metals in silicon	7990
J. Wong-Leung, J. S. Williams, A. Kinomura, Y. Nakano, Y. Hayashi, and D. J. Eaglesham	
Dissipative tunneling of a hole from Be to the valence band of GaAs	7999
A. Dargys and N. Žurauskienė	
Shallow to deep transformation of Se donors in GaSb under hydrostatic pressure	8003
H. Navarro-Contreras, F. de Anda-Salazar, J. Olvera-Hernández, Leonardo Hsu, M. D. McCluskey, and E. E. Haller	
Photoluminescence of electron-irradiated 4H-SiC	8008
T. Egilsson, A. Henry, I. G. Ivanov, J. L. Lindström, and E. Janzén	
Femtosecond luminescence from partly redistributed nonequilibrium electrons in InAs	8015
H. Nansei, S. Tomimoto, S. Saito, and T. Suemoto	
Photoinduced charge carriers in conjugated polymer–fullerene composites studied with light-induced electron-spin resonance	8019
V. Dyakonov, G. Zorinians, M. Scharber, C. J. Brabec, R. A. J. Janssen, J. C. Hummelen, and N. S. Sariciftci	
Semiconductors II: surfaces, interfaces, microstructures, and related topics	
Anomalous relaxations and chemical trends at III-V semiconductor nitride nonpolar surfaces	8026
Alessio Filippetti, Vincenzo Fiorentini, Giancarlo Cappellini, and Andrea Bosin	
Structure of Se-adsorbed GaAs(111)A-(2√3×2√3)-R30° surface	8032
Akihiro Ohtake, Takuji Komura, Takashi Hanada, Shiro Miwa, Tetsuji Yasuda, Kenta Arai, and Takafumi Yao	
Anomalous tunneling conductances of spin-singlet $\nu=\frac{2}{3}$ edge states: Interplay of Zeeman splitting and long-range Coulomb interaction	8037
H. C. Lee	
Tip-induced band bending by scanning tunneling spectroscopy of the states of the tip-induced quantum dot on InAs(110)	8043
R. Dombrowski, Chr. Steinebach, Chr. Wittneven, M. Morgenstern, and R. Wiesendanger	
Quantum turbulence and resonant tunneling	8049
Mark Ya. Azbel'	
Structural and compositional dependences of the Schottky barrier in Al/Ga _{1-x} Al _x As(100) and (110) junctions	8054
J. Bardi, N. Binggeli, and A. Baldereschi	
Liquid-crystal phases of quantum Hall systems	8065
Eduardo Fradkin and Steven A. Kivelson	
Ensemble density-functional approach to charge-spin textures in inhomogeneous quantum Hall systems	8073
O. Heinonen, J. M. Kinaret, and M. D. Johnson	
Beyond paired quantum Hall states: Parafermions and incompressible states in the first excited Landau level	8084
N. Read and E. Rezayi	
Photoluminescence in modulation-doped GaAs/Ga _{1-x} Al _x As heterojunctions	8093
J. X. Shen, Y. Oka, C. Y. Hu, W. Ossau, G. Landwehr, K.-J. Friedland, R. Hey, K. Ploog, and G. Weimann	
Thermal-conductivity measurements of GaAs/AlAs superlattices using a picosecond optical pump-and-probe technique	8105
W. S. Capinski, H. J. Maris, T. Ruf, M. Cardona, K. Ploog, and D. S. Katzer	

Structural properties of BeTe/ZnSe superlattices	8114
T. Walter, A. Rosenauer, R. Wittmann, D. Gerthsen, F. Fischer, T. Gerhard, A. Waag, G. Landwehr, P. Schunk, and T. Schimmel	
Initial stages of Al growth from dimethylaluminum hydride on silicon	8123
Toshiyuki Mitsui, Eric Hill, Robert Curtis, and Eric Ganz	
Lattice vibration of $\text{ZnSe}_{1-x}\text{Te}_x$ epilayers grown by molecular-beam epitaxy	8128
C. S. Yang, W. C. Chou, D. M. Chen, C. S. Ro, J. L. Shen, and T. R. Yang	
Exact results for a composite-fermion wave function	8132
Orion Ciftja	
Impurity states in semiconductors calculated via tight binding: A parameter sensitivity study	8137
J. G. Menchero and Timothy B. Boykin	
Quantum Hall-insulator transitions in lattice models with strong disorder	8144
Kun Yang and R. N. Bhatt	
Cyclotron-Stark-phonon resonances in semiconductor superlattices under terahertz irradiation	8152
V. V. Bryksin and P. Kleinert	
Aharonov-Bohm effect and resonances in the circular quantum billiard with two leads	8163
Suhan Ree and L. E. Reichl	
Subdecoherent information encoding in a quantum-dot array	8170
Paolo Zanardi and Fausto Rossi	
Schottky barriers on GaAs: Screened pinning at defect levels	8182
Timothy J. Drummond	
Surface physics, low-dimensional systems, and related topics	
Adsorbates on Gd(0001): A combined scanning tunneling microscopy and photoemission study	8195
Mathias Getzlaff, Matthias Bode, Rene Pascal, and Roland Wiesendanger	
Description of deformed atomic clusters within a projected spherical basis	8209
A. A. Raduta, Ad. R. Raduta, and Al. H. Raduta	
Formation of negative halogen ions in grazing scattering from an Al(111) surface: Multielectron effects	8218
A. G. Borisov, D. Teillet-Billy, J. P. Gauyacq, J. A. M. C. Silva, A. Mertens, C. Auth, and H. Winter	
Peierls-Nabarro model of interfacial misfit dislocation: An analytic solution	8232
Yugui Yao, Tsuchiang Wang, and Chongyu Wang	
Bulk and surface processes in low-energy-electron-induced decomposition of CaF_2	8237
R. Bennewitz, D. Smith, and M. Reichling	
Wetting and adsorption of ammonia on magnesium oxide	8247
D. E. Johnson and J. Z. Larese	
Adatom diffusion on a square lattice: Comparison of real-space renormalization group and Monte Carlo approaches	8252
A. A. Tarasenko, L. Jastrabík, F. Nieto, and C. Uebing	
Surface acoustic wave resonances in the spreading of viscous fluids	8262
G. McHale, M. K. Banerjee, M. I. Newton, and V. V. Krylov	
Electronic and magnetic properties of nanographite ribbons	8271
Katsunori Wakabayashi, Mitsutaka Fujita, Hiroshi Ajiki, and Manfred Sigrist	
Polymerization and decomposition of C_{60} on Pt(111) surfaces	8283
Nathan Swami, Hong He, and Bruce E. Koel	
Photoemission study of K on graphite	8292
P. Bennich, C. Puglia, P. A. Brühwiler, A. Nilsson, A. J. Maxwell, A. Sandell, N. Mårtensson, and P. Rudolf	
Possibility of long-range order in clean mesoscopic cylinders	8305
M. Lisowski, E. Zipper, and M. Stebelski	

CONTENTS - *Continued*

PHYSICAL REVIEW B

THIRD SERIES, VOLUME 59, NUMBER 12

15 MARCH 1999-II

Surface migration during diamond growth studied by molecular orbital calculations	8315
Karin Larsson and Jan-Otto Carlsson	
Cumulative Author Index	8323